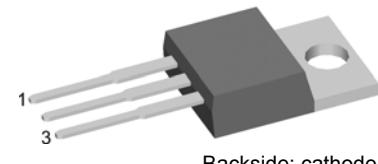
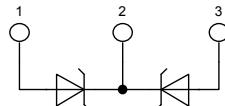


## Schottky Diode Gen 2

High Performance Schottky Diode  
Low Loss and Soft Recovery  
Common Cathode

### Part number

DSA 30 C 200 PB



Backside: cathode

### Features / Advantages:

- Very low  $V_f$
- Extremely low switching losses
- low  $I_{rm}$  values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

### Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

### Package:

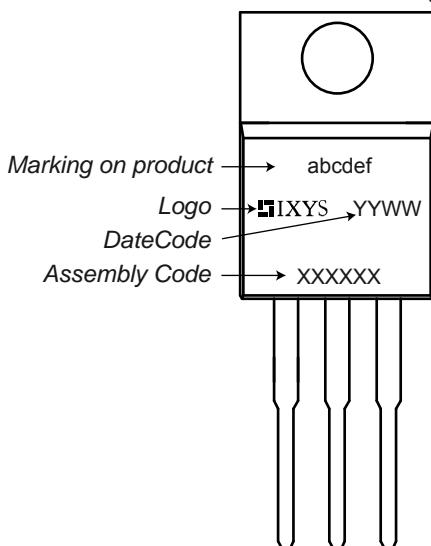
- Housing: TO-220
- Industry standard outline
- Epoxy meets UL 94V-0
- RoHS compliant

| Symbol            | Definition   | Conditions                           |                              | Ratings                      |      |     |
|-------------------|--|--------------------------------------|------------------------------|------------------------------|------|-----|
|                   |  | min.                                 | typ.                         | max.                         | Unit |     |
| $V_{RRM}$         | max. repetitive reverse voltage  |                                      |                              | 200                          |      | V   |
| $I_R$             | reverse current  | $V_R = 200\text{V}$                  | $T_{VJ} = 25^\circ\text{C}$  |                              | 0.25 | mA  |
|                   |  | $V_R = 200\text{V}$                  | $T_{VJ} = 125^\circ\text{C}$ |                              | 2.5  | mA  |
| $V_F$             | forward voltage  | $I_F = 15\text{A}$                   | $T_{VJ} = 25^\circ\text{C}$  |                              | 0.94 | V   |
|                   |  | $I_F = 30\text{A}$                   |                              |                              | 1.10 | V   |
|                   |  | $I_F = 15\text{A}$                   | $T_{VJ} = 125^\circ\text{C}$ |                              | 0.78 | V   |
|                   |  | $I_F = 30\text{A}$                   |                              |                              | 0.95 | V   |
| $I_{FAV}$         | average forward current  | rectangular                          | $d = 0.5$                    | $T_c = 150^\circ\text{C}$    |      | A   |
| $V_{F0}$<br>$r_F$ | threshold voltage<br>slope resistance }<br>for power loss calculation only |                                      |                              | $T_{VJ} = 175^\circ\text{C}$ | 0.53 | V   |
|                   |  |                                      |                              |                              | 10.8 | mΩ  |
| $R_{thJC}$        | thermal resistance junction to case  |                                      |                              |                              | 1.75 | K/W |
| $T_{VJ}$          | virtual junction temperature   |                                      |                              | -55                          | 175  | °C  |
| $P_{tot}$         | total power dissipation  |                                      |                              | $T_c = 25^\circ\text{C}$     | 85   | W   |
| $I_{FSM}$         | max. forward surge current   | $t = 10\text{ ms}$ (50 Hz), sine     |                              | $T_{VJ} = 45^\circ\text{C}$  |      | A   |
| $C_J$             | junction capacitance   | $V_R = 24\text{V}; f = 1\text{ MHz}$ |                              | $T_{VJ} = 25^\circ\text{C}$  | 67   | pF  |

| Symbol        | Definition                          | Conditions                 | Ratings |      |      |     |
|---------------|-------------------------------------|----------------------------|---------|------|------|-----|
|               |                                     |                            | min.    | typ. | max. |     |
| $I_{RMS}$     | RMS current                         | per terminal <sup>1)</sup> |         |      | 35   | A   |
| $R_{thCH}$    | thermal resistance case to heatsink |                            |         | 0.50 |      | K/W |
| $T_{stg}$     | storage temperature                 |                            | -55     |      | 150  | °C  |
| <b>Weight</b> |                                     |                            |         | 2    |      | g   |
| $M_D$         | mounting torque                     |                            | 0.4     |      | 0.6  | Nm  |
| $F_c$         | mounting force with clip            |                            | 20      |      | 60   | N   |

<sup>1)</sup>  $I_{RMS}$  is typically limited by the pin-to-chip resistance (1); or by the current capability of the chip (2).  
In case of (1) and a common cathode/anode configuration with a non-isolated backside,  
the current capability can be increased by connecting the backside.

### Product Marking

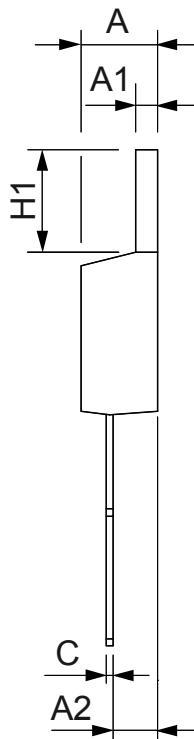
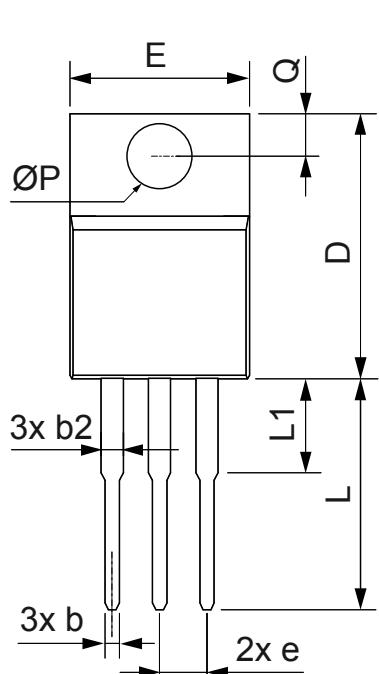


### Part number

D = Diode  
 S = Schottky Diode  
 A = low VF  
 30 = Current Rating [A]  
 C = Common Cathode  
 200 = Reverse Voltage [V]  
 PB = TO-220AB (3)

| Ordering | Part Name       | Marking on Product | Delivering Mode | Base Qty | Code Key |
|----------|-----------------|--------------------|-----------------|----------|----------|
| Standard | DSA 30 C 200 PB | DSA30C200PB        | Tube            | 50       | 507014   |

## Outlines TO-220



| Dim. | Millimeter |       | Inches |       |
|------|------------|-------|--------|-------|
|      | Min.       | Max.  | Min.   | Max.  |
| A    | 4.32       | 4.82  | 0.170  | 0.190 |
| A1   | 1.14       | 1.39  | 0.045  | 0.055 |
| A2   | 2.29       | 2.79  | 0.090  | 0.110 |
| b    | 0.64       | 1.01  | 0.025  | 0.040 |
| b2   | 1.15       | 1.65  | 0.045  | 0.065 |
| C    | 0.35       | 0.56  | 0.014  | 0.022 |
| D    | 14.73      | 16.00 | 0.580  | 0.630 |
| E    | 9.91       | 10.66 | 0.390  | 0.420 |
| e    | 2.54       | BSC   | 0.100  | BSC   |
| H1   | 5.85       | 6.85  | 0.230  | 0.270 |
| L    | 12.70      | 13.97 | 0.500  | 0.550 |
| L1   | 2.79       | 5.84  | 0.110  | 0.230 |
| ØP   | 3.54       | 4.08  | 0.139  | 0.161 |
| Q    | 2.54       | 3.18  | 0.100  | 0.125 |